

# 2N3771, 2N3772

2N3771 is a Preferred Device

## High Power NPN Silicon Power Transistors

These devices are designed for linear amplifiers, series pass regulators, and inductive switching applications.

### Features

- Forward Biased Second Breakdown Current Capability  
 $I_{S/b} = 3.75 \text{ Adc @ } V_{CE} = 40 \text{ Vdc} - 2N3771$   
 $= 2.5 \text{ Adc @ } V_{CE} = 60 \text{ Vdc} - 2N3772$
- Pb-Free Packages are Available\*

### MAXIMUM RATINGS (Note 1)

| Rating                                                                                 | Symbol         | 2N3771       | 2N3772    | Unit                     |
|----------------------------------------------------------------------------------------|----------------|--------------|-----------|--------------------------|
| Collector-Emitter Voltage                                                              | $V_{CEO}$      | 40           | 60        | Vdc                      |
| Collector-Emitter Voltage                                                              | $V_{CEX}$      | 50           | 80        | Vdc                      |
| Collector-Base Voltage                                                                 | $V_{CB}$       | 50           | 100       | Vdc                      |
| Emitter-Base Voltage                                                                   | $V_{EB}$       | 5.0          | 7.0       | Vdc                      |
| Collector Current – Continuous Peak                                                    | $I_C$          | 30<br>30     | 20<br>30  | Adc                      |
| Base Current – Continuous Peak                                                         | $I_B$          | 7.5<br>15    | 5.0<br>15 | Adc                      |
| Total Device Dissipation @ $T_C = 25^\circ\text{C}$<br>Derate above $25^\circ\text{C}$ | $P_D$          | 150<br>0.855 |           | W<br>W/ $^\circ\text{C}$ |
| Operating and Storage Junction Temperature Range                                       | $T_J, T_{stg}$ | -65 to +200  |           | $^\circ\text{C}$         |

### THERMAL CHARACTERISTICS

| Characteristic                       | Symbol        | Max  | Unit               |
|--------------------------------------|---------------|------|--------------------|
| Thermal Resistance, Junction-to-Case | $\theta_{JC}$ | 1.17 | $^\circ\text{C/W}$ |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Indicates JEDEC registered data.

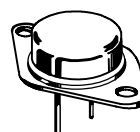


**ON Semiconductor®**

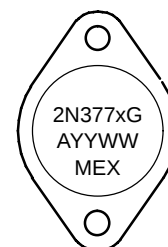
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**20 and 30 AMPERE  
POWER TRANSISTORS  
NPN SILICON  
40 and 60 VOLTS, 150 WATTS**

### MARKING DIAGRAM



**TO-204AA (TO-3)  
CASE 1-07  
STYLE 1**



2N377x = Device Code  
x = 1 or 2  
G = Pb-Free Package  
A = Assembly Location  
YY = Year  
WW = Work Week  
MEX = Country of Origin

### ORDERING INFORMATION

| Device  | Package             | Shipping         |
|---------|---------------------|------------------|
| 2N3771  | TO-204              | 100 Units / Tray |
| 2N3771G | TO-204<br>(Pb-Free) | 100 Units / Tray |
| 2N3772  | TO-204              | 100 Units / Tray |
| 2N3772G | TO-204<br>(Pb-Free) | 100 Units / Tray |

**Preferred** devices are recommended choices for future use and best overall value.

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

## 2N3771, 2N3772

### ELECTRICAL CHARACTERISTICS ( $T_C = 25^\circ\text{C}$ unless otherwise noted)

| Characteristic                                                                                                                                                                                                                                                                                                                                                                                                                      |                                                | Symbol         | Min                    | Max                           | Unit |
|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------------------------------------------|----------------|------------------------|-------------------------------|------|
| <b>OFF CHARACTERISTICS</b>                                                                                                                                                                                                                                                                                                                                                                                                          |                                                |                |                        |                               |      |
| Collector-Emitter Sustaining Voltage (Note 2 and 3)<br>( $I_C = 0.2\text{ Adc}$ , $I_B = 0$ )                                                                                                                                                                                                                                                                                                                                       | 2N3771<br>2N3772                               | $V_{CEO(sus)}$ | 40<br>60               | –<br>–                        | Vdc  |
| Collector-Emitter Sustaining Voltage<br>( $I_C = 0.2\text{ Adc}$ , $V_{EB(off)} = 1.5\text{ Vdc}$ , $R_{BE} = 100\ \Omega$ )                                                                                                                                                                                                                                                                                                        | 2N3771<br>2N3772                               | $V_{CEX(sus)}$ | 50<br>80               | –<br>–                        | Vdc  |
| Collector-Emitter Sustaining Voltage<br>( $I_C = 0.2\text{ Adc}$ , $R_{BE} = 100\ \Omega$ )                                                                                                                                                                                                                                                                                                                                         | 2N3771<br>2N3772                               | $V_{CER(sus)}$ | 45<br>70               | –<br>–                        | Vdc  |
| Collector Cutoff Current (Note 2)<br>( $V_{CE} = 30\text{ Vdc}$ , $I_B = 0$ )<br>( $V_{CE} = 50\text{ Vdc}$ , $I_B = 0$ )<br>( $V_{CE} = 25\text{ Vdc}$ , $I_B = 0$ )                                                                                                                                                                                                                                                               | 2N3771<br>2N3772                               | $I_{CEO}$      | –<br>–                 | 10<br>10                      | mAdc |
| Collector Cutoff Current (Note 2)<br>( $V_{CE} = 50\text{ Vdc}$ , $V_{EB(off)} = 1.5\text{ Vdc}$ )<br>( $V_{CE} = 100\text{ Vdc}$ , $V_{EB(off)} = 1.5\text{ Vdc}$ )<br>( $V_{CE} = 45\text{ Vdc}$ , $V_{EB(off)} = 1.5\text{ Vdc}$ )<br>( $V_{CE} = 30\text{ Vdc}$ , $V_{EB(off)} = 1.5\text{ Vdc}$ , $T_C = 150^\circ\text{C}$ )<br><br>( $V_{CE} = 45\text{ Vdc}$ , $V_{EB(off)} = 1.5\text{ Vdc}$ , $T_C = 150^\circ\text{C}$ ) | 2N3771<br>2N3772<br>2N6257<br>2N3771<br>2N3772 | $I_{CEV}$      | –<br>–<br>–<br>–<br>–  | 2.0<br>5.0<br>4.0<br>10<br>10 | mAdc |
| Collector Cutoff Current (Note 2)<br>( $V_{CB} = 50\text{ Vdc}$ , $I_E = 0$ )<br>( $V_{CB} = 100\text{ Vdc}$ , $I_E = 0$ )                                                                                                                                                                                                                                                                                                          | 2N3771<br>2N3772                               | $I_{CBO}$      | –<br>–                 | 2.0<br>5.0                    | mAdc |
| Emitter Cutoff Current (Note 2)<br>( $V_{BE} = 5.0\text{ Vdc}$ , $I_C = 0$ )<br>( $V_{BE} = 7.0\text{ Vdc}$ , $I_C = 0$ )                                                                                                                                                                                                                                                                                                           | 2N3771<br>2N3772                               | $I_{EBO}$      | –<br>–                 | 5.0<br>5.0                    | mAdc |
| <b>ON CHARACTERISTICS (Note 2)</b>                                                                                                                                                                                                                                                                                                                                                                                                  |                                                |                |                        |                               |      |
| DC Current Gain (Note 3)<br>( $I_C = 15\text{ Adc}$ , $V_{CE} = 4.0\text{ Vdc}$ )<br>( $I_C = 10\text{ Adc}$ , $V_{CE} = 4.0\text{ Vdc}$ )<br>( $I_C = 8.0\text{ Adc}$ , $V_{CE} = 4.0\text{ Vdc}$ )<br>( $I_C = 30\text{ Adc}$ , $V_{CE} = 4.0\text{ Vdc}$ )<br>( $I_C = 20\text{ Adc}$ , $V_{CE} = 4.0\text{ Vdc}$ )                                                                                                              | 2N3771<br>2N3772<br>2N3771<br>2N3772           | $h_{FE}$       | 15<br>15<br>5.0<br>5.0 | 60<br>60<br>–<br>–            | –    |
| Collector-Emitter Saturation Voltage<br>( $I_C = 15\text{ Adc}$ , $I_B = 1.5\text{ Adc}$ )<br>( $I_C = 10\text{ Adc}$ , $I_B = 1.0\text{ Adc}$ )<br>( $I_C = 30\text{ Adc}$ , $I_B = 6.0\text{ Adc}$ )<br>( $I_C = 20\text{ Adc}$ , $I_B = 4.0\text{ Adc}$ )                                                                                                                                                                        | 2N3771<br>2N3772<br>2N3771<br>2N3772           | $V_{CE(sat)}$  | –<br>–<br>–<br>–       | 2.0<br>1.4<br>4.0<br>4.0      | Vdc  |
| Base-Emitter On Voltage<br>( $I_C = 15\text{ Adc}$ , $V_{CE} = 4.0\text{ Vdc}$ )<br>( $I_C = 10\text{ Adc}$ , $V_{CE} = 4.0\text{ Vdc}$ )<br>( $I_C = 8.0\text{ Adc}$ , $V_{CE} = 4.0\text{ Vdc}$ )                                                                                                                                                                                                                                 | 2N3771<br>2N3772                               | $V_{BE(on)}$   | –<br>–                 | 2.7<br>2.2                    | Vdc  |
| <b>*DYNAMIC CHARACTERISTICS (Note 2)</b>                                                                                                                                                                                                                                                                                                                                                                                            |                                                |                |                        |                               |      |
| Current-Gain — Bandwidth Product<br>( $I_C = 1.0\text{ Adc}$ , $V_{CE} = 4.0\text{ Vdc}$ , $f_{test} = 50\text{ kHz}$ )                                                                                                                                                                                                                                                                                                             |                                                | $f_T$          | 0.2                    | –                             | MHz  |
| Small-Signal Current Gain<br>( $I_C = 1.0\text{ Adc}$ , $V_{CE} = 4.0\text{ Vdc}$ , $f = 1.0\text{ kHz}$ )                                                                                                                                                                                                                                                                                                                          |                                                | $h_{fe}$       | 40                     | –                             | –    |
| <b>SECOND BREAKDOWN</b>                                                                                                                                                                                                                                                                                                                                                                                                             |                                                |                |                        |                               |      |
| Second Breakdown Energy with Base Forward Biased, $t = 1.0\text{ s}$ (non-repetitive)<br>( $V_{CE} = 40\text{ Vdc}$ )<br>( $V_{CE} = 60\text{ Vdc}$ )                                                                                                                                                                                                                                                                               | 2N3771<br>2N3772                               | $I_{S/b}$      | 3.75<br>2.5            | –<br>–                        | Adc  |

2. Indicates JEDEC registered data.

3. Pulse Test: 300  $\mu\text{s}$ , Rep. Rate 60 cps.

## 2N3771, 2N3772

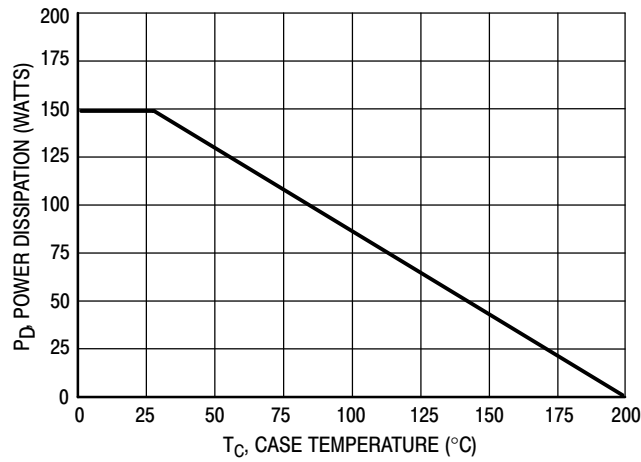


Figure 1. Power Derating

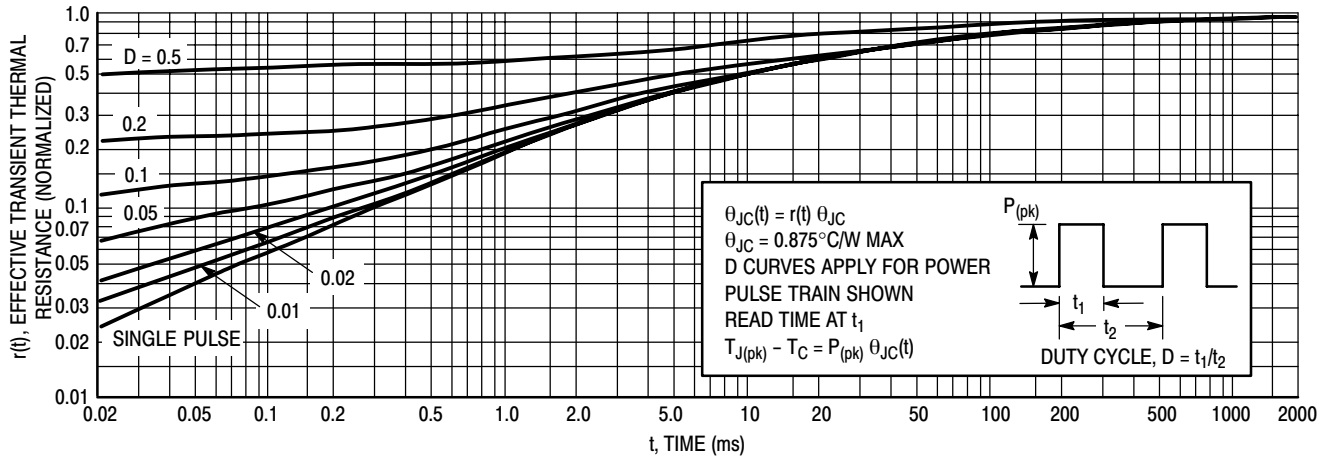


Figure 2. Thermal Response — 2N3771, 2N3772

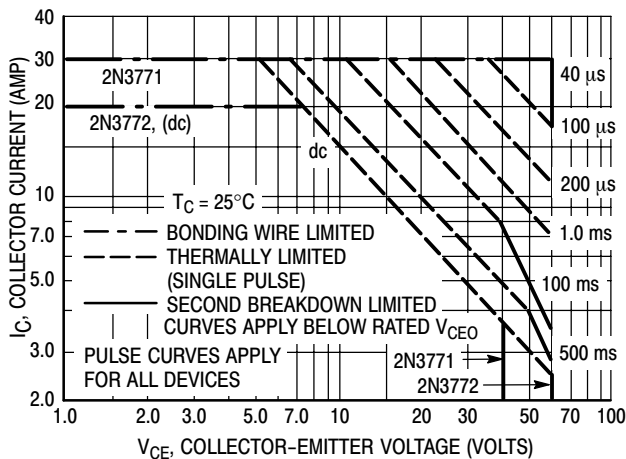


Figure 3. Active-Region Safe Operating Area — 2N3771, 2N3772

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate  $I_C - V_{CE}$  limits of the transistor that must be observed for reliable operation: i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

Figure 3 is based on JEDEC registered Data. Second breakdown pulse limits are valid for duty cycles to 10% provided  $T_{J(pk)} < 200^\circ\text{C}$ .  $T_{J(pk)}$  may be calculated from the data of Figure 2. Using data of Figure 2 and the pulse power limits of Figure 3,  $T_{J(pk)}$  will be found to be less than  $T_{J(max)}$  for pulse widths of 1 ms and less. When using ON Semiconductor transistors, it is permissible to increase the pulse power limits until limited by  $T_{J(max)}$ .

# 2N3771, 2N3772

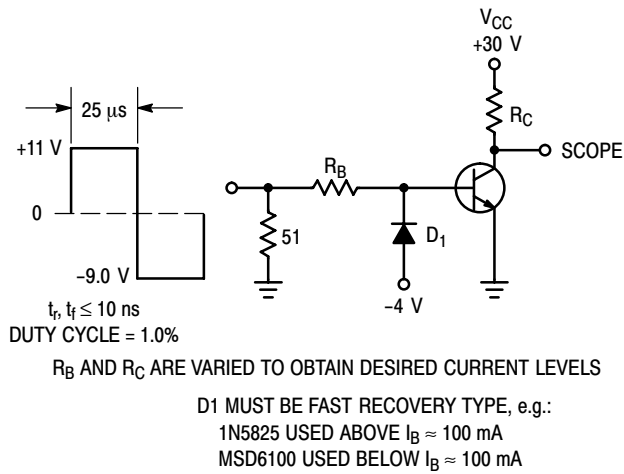


Figure 4. Switching Time Test Circuit

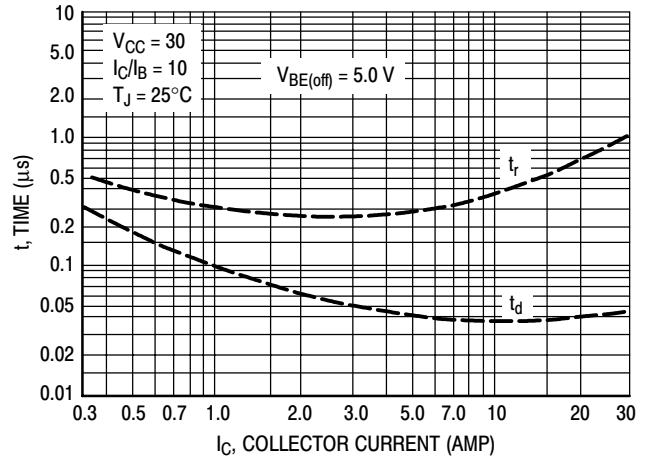


Figure 5. Turn-On Time

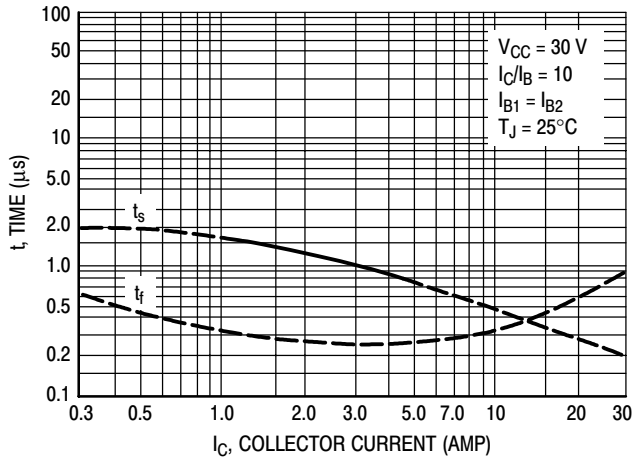


Figure 6. Turn-Off Time

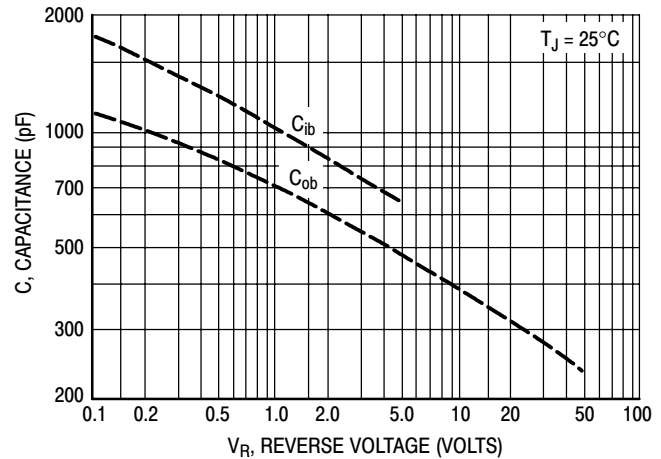


Figure 7. Capacitance

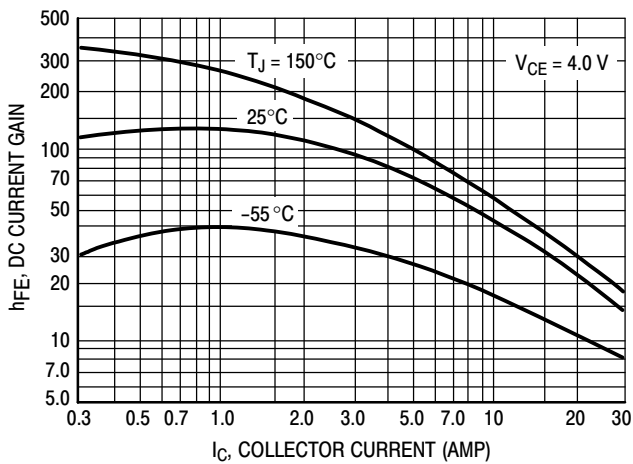


Figure 8. DC Current Gain

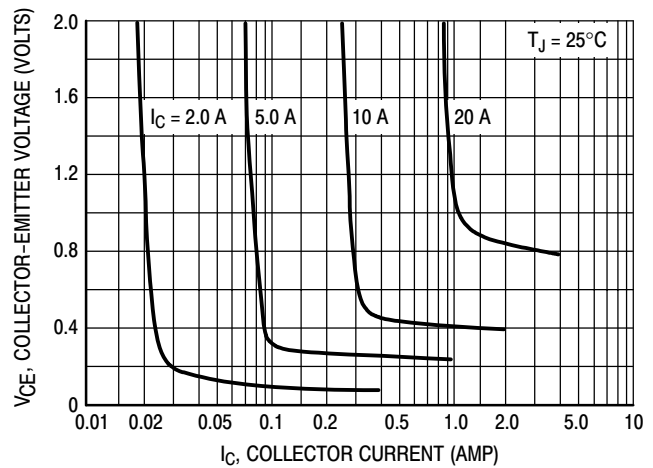


Figure 9. Collector Saturation Region

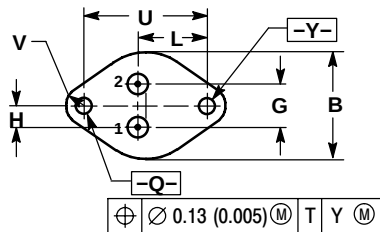
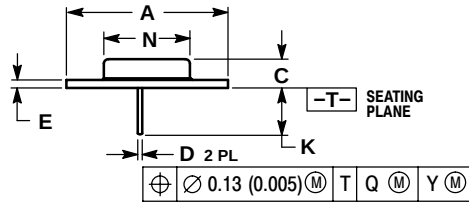
# 2N3771, 2N3772

## PACKAGE DIMENSIONS

### TO-204 (TO-3)

CASE 1-07

ISSUE Z



#### NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. ALL RULES AND NOTES ASSOCIATED WITH REFERENCED TO-204AA OUTLINE SHALL APPLY.

| DIM | INCHES    |       | MILLIMETERS |       |
|-----|-----------|-------|-------------|-------|
|     | MIN       | MAX   | MIN         | MAX   |
| A   | 1.550 REF |       | 39.37 REF   |       |
| B   | ---       | 1.050 | ---         | 26.67 |
| C   | 0.250     | 0.335 | 6.35        | 8.51  |
| D   | 0.038     | 0.043 | 0.97        | 1.09  |
| E   | 0.055     | 0.070 | 1.40        | 1.77  |
| G   | 0.430 BSC |       | 10.92 BSC   |       |
| H   | 0.215 BSC |       | 5.46 BSC    |       |
| K   | 0.440     | 0.480 | 11.18       | 12.19 |
| L   | 0.665 BSC |       | 16.89 BSC   |       |
| N   | ---       | 0.830 | ---         | 21.08 |
| Q   | 0.151     | 0.165 | 3.84        | 4.19  |
| U   | 1.187 BSC |       | 30.15 BSC   |       |
| V   | 0.131     | 0.188 | 3.33        | 4.77  |

#### STYLE 1:

1. BASE
  2. EMITTER
- CASE: COLLECTOR

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